# **ELECTRONICS DEVICES AND CIRCUITS SECTION - C TRANSISTORS**

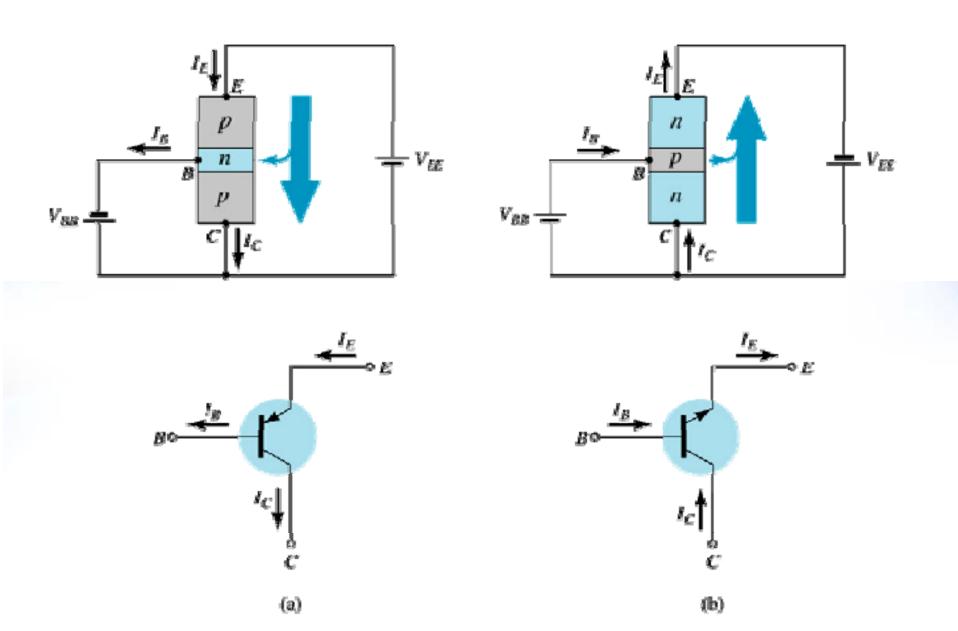
#### **OBJECTIVE**

BJT

### **CC** Configuration

### Common - Collector Configuration

- Also called emitter-follower (EF).
- It is called common-emitter configuration since both the signal source and the load share the collector terminal as a common connection point.
- The output voltage is obtained at emitter terminal.
- The input characteristic of common-collector configuration is similar with common-emitter. configuration.
- Common-collector circuit configuration is provided with the load resistor connected from emitter to ground.
- It is used primarily for impedance-matching purpose since it has high input impedance and low output impedance.



Notation and symbols used with the common-collector configuration: (a) pnp transistor; (b) npn transistor.

• For the common-collector configuration, the output characteristics are a plot of  $I_E$  vs  $V_{CE}$  for a range of values of  $I_B$ .

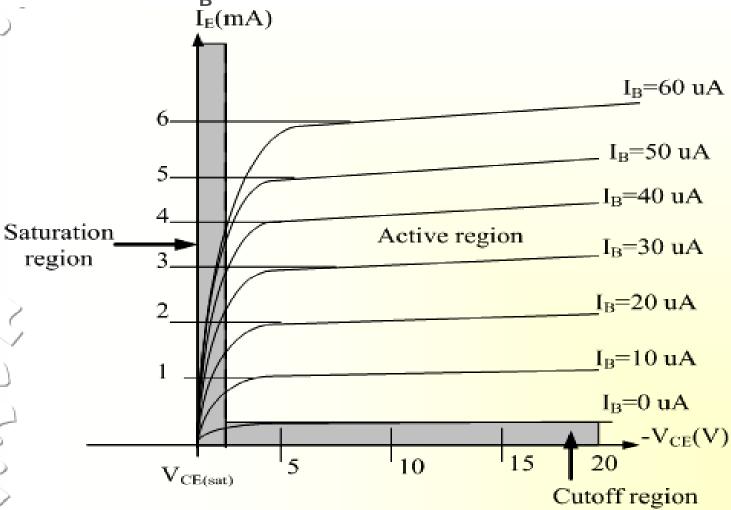


Fig 4.9: Output characteristic in CC configuration for npn transistor

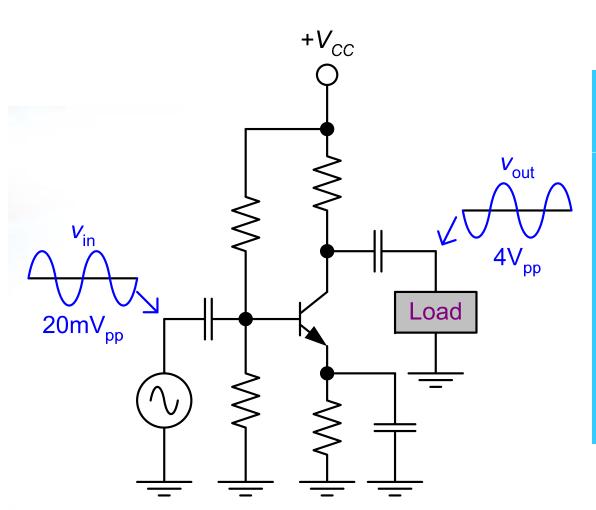
### **BJT Amplifier Configurations**

- Common-emitter (CE) amplifier
- Common-collector (CC) amplifier
- Common-base (CB) amplifier

### Property ranges.

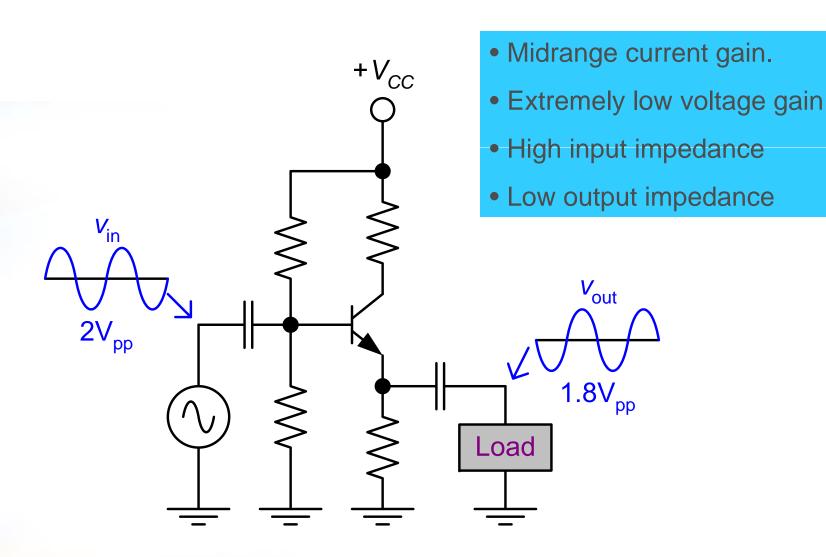
| Property  | Low   | Midrange | High  |
|-----------|-------|----------|-------|
| Gain      | < 100 | 100-1000 | >1000 |
| Impedance | <1kΩ  | 1kΩ-10kΩ | >10kΩ |

## Common-emitter (CE) amplifier.



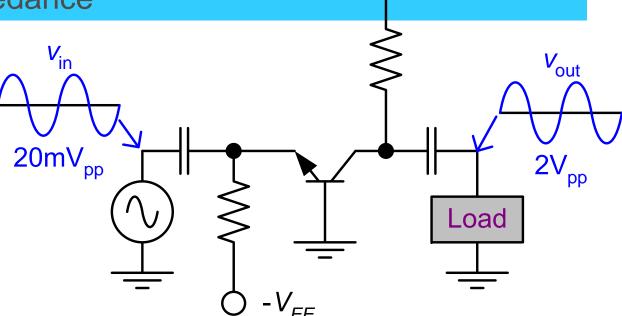
- Midrange values of voltage and current gain.
- High power gain
- Midrange input impedance
- Midrange output impedance

### Common-collector (CC) amplifier.



### Common-base (CB) amplifier.

- Midrange voltage gain
- Extremely low current gain (slightly less than 1)
- Low input impedance
- High output impedance



### A comparison of CE, CC, and CB circuit characteristics.

| Type | $A_{\nu}$ | $A_i$    | $A_p$         | <b>Z</b> in | <b>Z</b> out |
|------|-----------|----------|---------------|-------------|--------------|
| CE   | Midrange  | Midrange | High          | Midrange    | Midrange     |
| CC   | < 1       | Midrange | $\cong A_i$   | High        | Low          |
| СВ   | Midrange  | < 1      | $\cong A_{V}$ | Low         | High         |

$$\left(A_p = A_{\nu} A_i\right)$$

#### **BJT Terminal Connections**

| Type | Emitter | Base   | Collector |
|------|---------|--------|-----------|
| CE   | Common  | Input  | Output    |
| CC   | Output  | Input  | Common    |
| СВ   | Input   | Common | Output    |